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Lipeles et al.

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[54] METALLO-ORGANIC SOLUTION DEPOSITION (MOSD) OF TRANSPARENT, CRYSTALLINE FERROELECTRIC FILMS

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[58] Field of Search 427/162, 100, 108, 110, 427/126.2, 126.3, 240, 421, 430.1, 443.2, 226

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[57] ABSTRACT

An improved process to deposit transparent, crystalline, ferroelectric films from metallo-organic solutions on platinum, glass, quartz, and sapphire substrates is disclosed. The use of this process results in a significant improvement in the transparency of perovskite, ferroelectric lead titanate (PT), lead zirconate titanate (PZT) and doped-PZT films (e.g. films doped with lanthanum, PLZT).

7 Claims, 20 Drawing Sheets